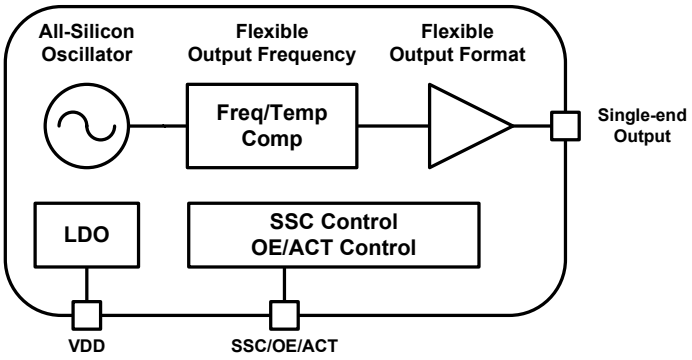
AS5016 Tiny LVCMOS Spread Spectrum Silicon Oscillator

Description

The AS5016 all-silicon oscillator utilizes digital frequency synthesis and sensing technologies to provide a quartz-free, MEMS-free, low-jitter clock at any output frequency. The device is factory-programmed to a fixed frequency ranging from 10 kHz to 125 MHz with 1 Hz resolution and maintains low jitter across its operating range. It uses on-chip temperature and strain sensors and an advanced LC tank architecture to achieve excellent reliability even in high-impact shock scenarios.

AS5016's on-chip power supply filtering provides ease of use in noisy systems with switched-mode power supplies. Offered in an industry-standard 1210 package, the AS5016 supports optional SSC control with down-spread or center-spread modulation for EMI reduction in space-constrained applications.



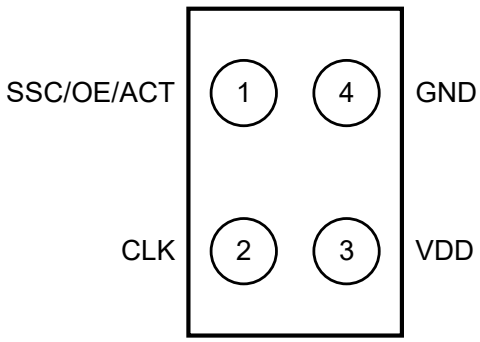
Key Features

- Quartz-free and MEMS-free without mechanical moving parts
- LVCMOS output: 10 kHz to 125 MHz
- Low jitter: 1 ps Typ
  (12 kHz – 20 MHz, @125 MHz)
- Programmable spread spectrum (SSC):
  - Center or down spread
  - Up to ±1.5% center or -3% down deviation
- Operating temperature range:
  - -40 to 85 ℃ (Industial grade)
  - -40 to 105 ℃ (Extended-Industial grade)
  - -40 to 125 ℃ (AEC-Q100 grade 1)
- Frequency tolerance: ±50 ppm (-40 to 125 ℃)
- Immunity to shock and vibration
- Integrated LDO for on-chip power supply noise filtering
- Support 1.8V, 2.5V, 3.3V V_{DD} supply operation
- Tiny package size: 1.2 mm x 1.0 mm

Application

- IoT, Wearable device
- Medical, Industrial automation
- ADAS ECUs
- Automotive networking
- Lidar/Radar sensors
- Camera/Vision system

Pin definition



Top view

Pin#	Description
1	OE = Output enable. Active high ACT = Device active. Active high SSC = Spread spectrum clock enable
2	GND = Ground
3	CLK = Clock output
4	VDD = Power supply

1. Ordering Guide

XO Series	Description
5016	Spread Spectrum

	Device Type
A	General
B	Factory defined setting

	Package
F	1210

	Device Grade	Temperature Grade
I	Industrial grade	-40 to 85°C
E	Extended industrial grade	-40 to 105°C
A[2]	Automotive grade	-40 to 125°C

5016	A	A	-	-	-	-	-	F	B	I	T

Device Revision

	Pin#1 Func
A	OE
B	ACT
C	SSC

Configuration Code[1]	Description
xxxxx	Five digit numeric code

Spread direction and frequency deviation can be specified per the supported options. format. A unique five digit numeric code will be assigned for the specific combination of settings.

Code	Packing type	Qty
T	7-inch reel	250
R	13-inch reel	2500
F	13-inch reel	5000
<blank>	Bulk	Sample

Note:

1. The five-digit numeric code is an identification of the configurations. Check the datasheet appendix for the details.
2. Contact aeonsemi.com/contact_us for automotive grade option.

2. Electrical Specifications

Table 2.1. Electrical Specifications

Parameter	Symbol	Min	Typ	Max	Unit	Note
Operating Temperature Range						
Temperature Range	T_A	-40	–	85	℃	Industrial grade
		-40	–	105	℃	Extended industrial grade
		-40	–	125	℃	Automotive AEC-Q100 Grade1
Supply Voltage and Power Consumption						
Supply Voltage	V_{DD}	1.62	–	3.63	V	
Supply Current (F_{CLK} = 25 MHz)	I_{DD}	–	10	11	mA	Tristate Hi-Z (OE = 0)
		–	1	2	mA	Ready State (ACT = 0)
		–	12	14	mA	LVCMOS output (C_L=15pF)
Frequency Range						
Frequency Range	F_{CLK}	0.01	–	125	MHz	LVCMOS output
Frequency Tolerance						
Total frequency tolerance	F_{TOTAL}	-50	–	50	ppm	-40 - 105℃
Notes: Inclusive of initial frequency tolerance at 25℃, temperature stability over the corresponding operation temperature range, 10-year aging at 25℃ and variations over supply voltage, load and humidity after soldering-reflow shift settles.						
IO Characteristics						
Output enable (OE)	V_{IH}	0.7×V_{DD}	–	–	V	Input high voltage
	V_{IL}	–	–	0.3×V_{DD}	V	Input low voltage
	R_{PUP}	–	50	–	kΩ	Internal pull-up resistor to V_{DD}
	T_D	–	–	3	us	Output disable time, F_{CLK} >10 MHz
	T_E	–	–	20	us	Output enable time, F_{CLK} >10 MHz
Device active (ACT)	V_{IH}	0.7×V_{DD}	–	–	V	Input high voltage
	V_{IL}	–	–	0.3×V_{DD}	V	Input low voltage
	R_{PUP}	–	50	–	kΩ	Internal pull-up resistor to V_{DD}
	T_D	–	–	3	us	Output disable time, F_{CLK} >10 MHz
	T_S	–	–	40	us	Device standby time, F_{CLK} >10 MHz
	T_E	–	–	400	us	Device enable time, F_{CLK} >10 MHz
Spread spectrum control (SSC)	V_{IH}	0.7×V_{DD}	–	–	V	Input high voltage
	V_{IL}	–	–	0.3×V_{DD}	V	Input low voltage
	R_{PUP}	–	50	–	kΩ	Internal pull-up resistor to V_{DD}
Spread Spectrum (SSC) Characteristics						
Modulation frequency	f_{MOD}	–	31.25	–	kHz	Triangle modulation waveform
Frequency deviation	Δf	-3	–	0	%	Down-spread
	Δf	-1.5	–	1.5	%	Center-spread
Output Characteristics						
Powerup time	T_{OSC}	–	–	4	ms	Time from power reaches 0.9 × V_{DD} to output frequency (F_{CLK}) within spec
Duty cycle	DC	45	–	55	%	LVCMOS (C_L=15pF)
Rise/Fall time (20% to 80% VPP)	$T_{R/F}$	–	0.5	1.5	ns	LVCMOS (C_L=15pF)
LVCMOS	V_{OH}	0.83×V_{DD}	–	–	V	C_L=15pF
	V_{OL}	–	–	0.17×V_{DD}	V	

Continued on next page

Parameter	Symbol	Min	Typ	Max	Unit	Note
Phase Noise and Jitter						
RMS jitter	R_J	–	1	1.5	ps	F_{CLK} >= 100 MHz
BW: 12k - 20MHz		–	1.5	2	ps	F_{CLK} >= 25 MHz
Phase noise	PN_{1k}	–	-73	–	dBc/Hz	Phase noise at 1kHz offset
125MHz LVCMOS output	PN_{10k}	–	-103	–	dBc/Hz	Phase noise at 10kHz offset
V_{DD} = 1.8 - 3.3V	PN_{100k}	–	-126	–	dBc/Hz	Phase noise at 100kHz offset
	PN_{1M}	–	-141	–	dBc/Hz	Phase noise at 1MHz offset
	PN_{10M}	–	-150	–	dBc/Hz	Phase noise at 10MHz offset
PSNR						
Spurs from power noise	PSNR	–	-76	–	dBc	100 kHz sine wave
50mV ripple		–	-75	–	dBc	200 kHz sine wave
V_{DD} = 1.8V		–	-75	–	dBc	500 kHz sine wave
		–	-75	–	dBc	1 MHz sine wave
Spurs from power noise	PSNR	–	-83	–	dBc	100 kHz sine wave
50mV ripple		–	-83	–	dBc	200 kHz sine wave
V_{DD} = 2.5 or 3.3V		–	-83	–	dBc	500 kHz sine wave
		–	-82	–	dBc	1 MHz sine wave

Table 2.2. Environmental Compliance and Package Information

Parameter	Value
Moisture sensitivity level (MSL)	3

Notes:

For additional product information not listed in the data sheet (e.g. RoHS Certifications, MSDS data, qualification data, REACH Declarations, ECCN codes, etc.), contact aeonsemi.com/contact_us

Table 2.3. Absolute Maximum Ratings[1]

Parameter	Symbol	Rating	Unit
Maximum operating temperature	T_{AMAX}	125	℃
Storage temperature	T_S	-55 - 125	℃
Supply voltage	V_{DD_MAX}	-0.5 - 3.8	V
Input voltage	V_{IN_MAX}	-0.5 - V_{DD}+0.3	V
ESD HBM (JESD22-A114)	HBM	4.0	kV
ESD CDM (JESD22-C101)	CDM	1.0	kV
Solder Temperature[2]	T_{PEAK}	260	℃
Solder time at T_{PEAK}[2]	T_P	20 - 40	sec

Notes:

1. Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.
2. The device is compliant with JEDEC J-STD-020.

3. Package Outline Drawing

Figure 3.1. shows the package outline drawing for the AS5016 devices. Details of dimension for different size options are listed in Table 3.1.

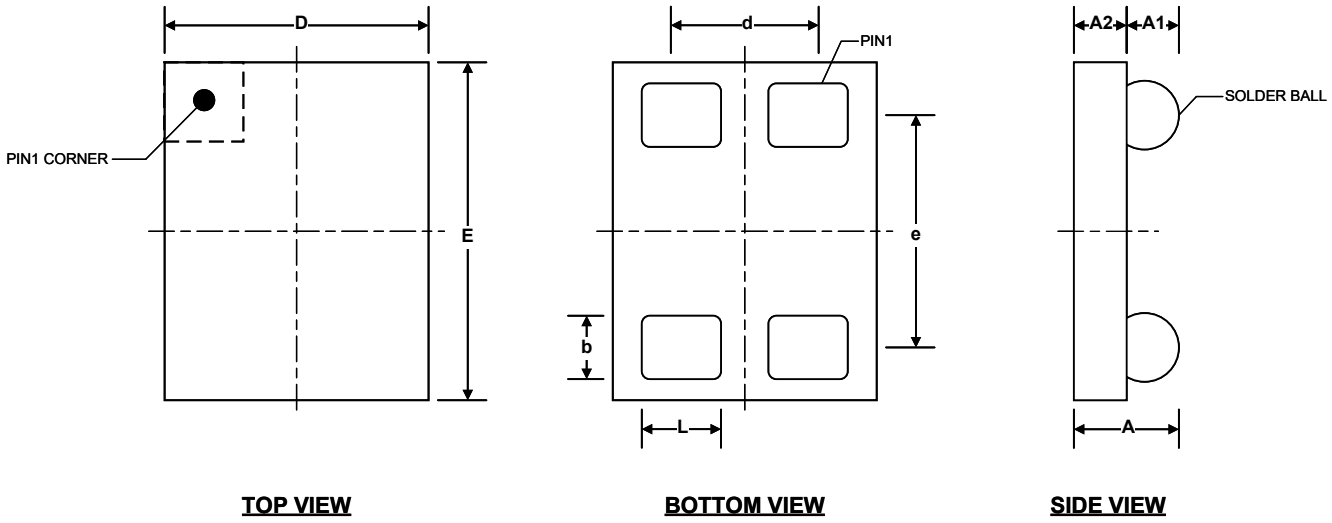


Figure 3.1. Package Outline Drawing

Table 3.1. Dimensions of Package Outline Drawing (um)

Symbol	Min	Nom	Max
A	505	540	575
A1	120	130	140
A2	385	410	435
b	225	235	245
d	–	410 BSC	–
D	1027.2	1052.2	1077.2
d	–	958.2 BSC	–
E	1243.2	1268.2	1293.2
L	250	260	270

4. Recommended PCB Land Pattern

Figure 4.1. shows the drawing of recommended PCB land pattern for the AS5016 devices. Details of dimension for different size options are listed in Table 4.1.

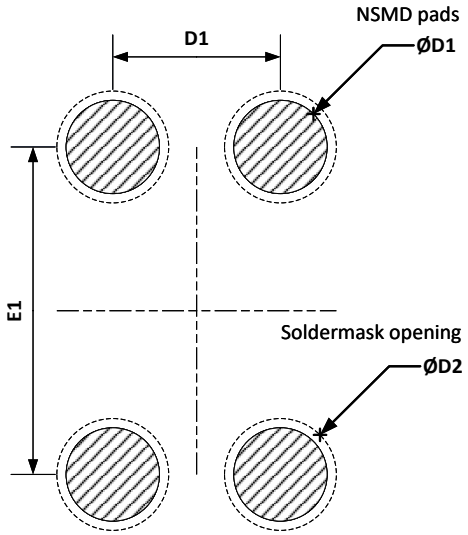


Figure 4.1. Recommended PCB Land Pattern

Table 4.1. Dimensions of Recommended PCB Land Pattern (mm)

Symbol	1210 Package
D1	0.41
ØD1	0.25
ØD2	0.35
E1	1.00

Notes:

The following notes and stencil design are shared as recommendations only. A customer or user may find it necessary to use different parameters and fine-tune their SMT process as required for their application and tooling.

General

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on the IPC-7351 guidelines.
4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

Stencil Design

1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
2. The stencil thickness should be 0.125 mm (5 mils).
3. The ratio of stencil aperture to land pad size should be 0.8 1 for the pads.

Card Assembly

1. A No-Clean, Type-3 solder paste is recommended.
2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

5. Top Mark

Figure 5.1. shows the top mark specifications for the AS5016 devices. Description of each line is listed in Table 5.1.

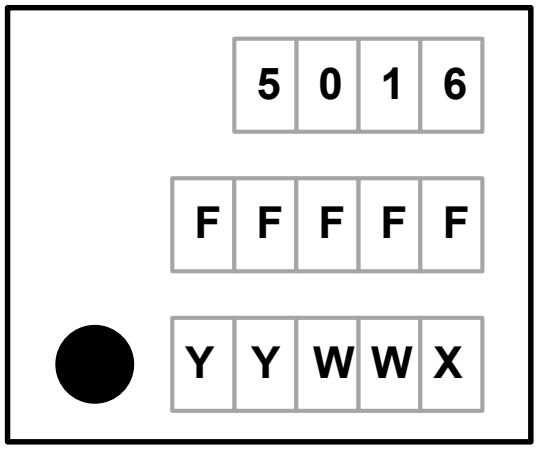


Figure 5.1. Top Mark

Table 5.1. Top Mark Description

Line	Position	Description
1	1-6	Device Name
2	1-5	Unique 5-digit Device Configuration Number
3	1	Pin 1 orientation mark (dot)
	2-3	Year (last two digits of the year), to be assigned by assembly site (ex: 2025 = 25)
	4-5	Calendar Work Week number (1-53), to be assigned by assembly site
	6	Manufacturer code

6. Packing Specification

Figure 6.1. shows the packing specifications for the AS5016 devices. Details of the tape specifications are listed in Table 6.1.
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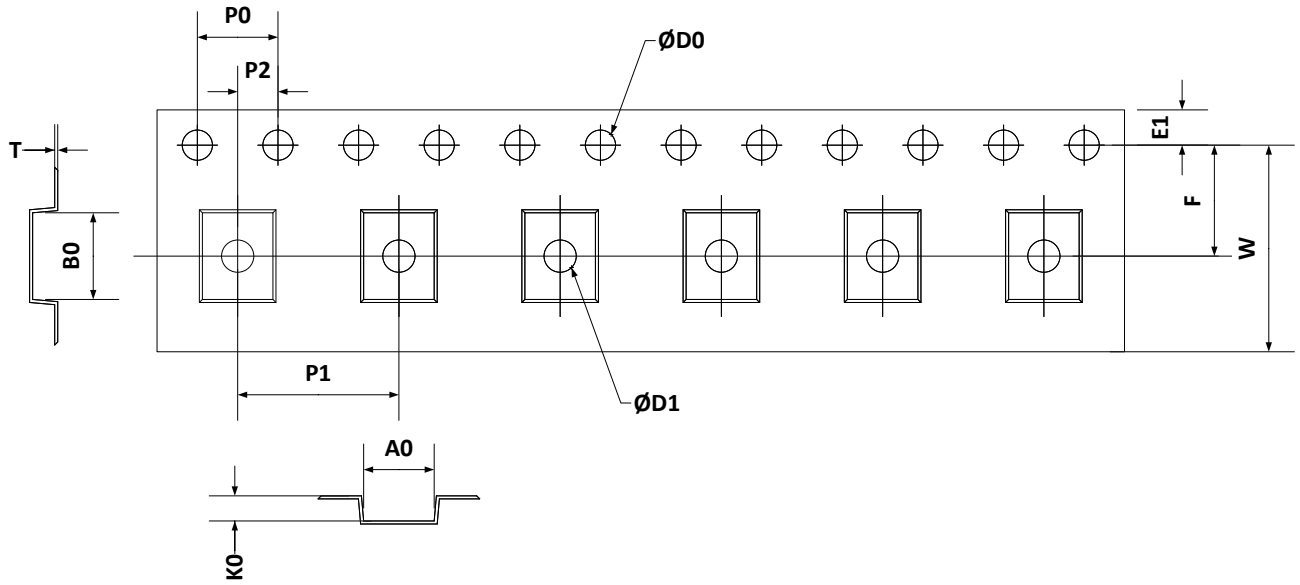

Figure 6.1. Tape Specification

Table 6.1. Dimensions of Tape (mm)

Symbol	1210 Package
A0	1.20 ± 0.03
B0	1.42 ± 0.03
K0	0.63 ± 0.03
E1	1.75 ± 0.10
F	3.50 ± 0.05
W	8.00 (+0.30/-0.10)
T	0.20 ± 0.02
P0	4.00 ± 0.10
P1	4.00 ± 0.10
P2	2.00 ± 0.05
ϕD0	1.55 ± 0.05
ϕD1	0.60 ± 0.05

7. Important Notice and Disclaimer

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8. Revision History

Revision	Date	Description
1.02	Oct 2026	Updated ordering guide
1.01	Oct 2026	Updated several items
0.10	Sep 2025	Corrected several description errors
0.09	Aug 2025	Update the package outline
0.08	May 2024	Correct several mistakes
0.07	Feb 2024	Update the initial tolerance and temperature stability
0.06	Sep 2023	Update the initial tolerance
0.05	Jul 2023	Update the top mark and ordering guide
0.04	Jun 2023	Correct C1AW transaction to C1EAW
0.03	Jun 2023	Add C1 data programming interface protocol
0.02	May 2023	Updated the core power consumption
0.01	Nov 2022	Initial release